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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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DOCUMENT COVER PAGE

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Note: This cover page establishes the Doc No., Title and current status of the attached document.

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Issue Level	Rev	Eff Date				
1	5	23-FEB-06				

Doc No.	SDSC-PSE-AN7135	13300 LCVC1		Zii Zaio
DOC NO.	3D30-F3E-AN7 133	1	5	23-FEB-06
Doc Title	Product Specifications for AN7135	Total no. of pag		7

Revision History

Issue	Rev	Eff Date	S/N	Page	Change Details	Remarks
1	4	15-FEB-04	1	-	Added this cover page.	
			2	6	Removed this page.	
			3	6A	Added this page for leadfree specification.	
			4	6A	Amended Outer Lead Surface Process &	
		***************************************			Chip Mounting Method.	
					Only Mounting Method.	
	5	23-FEB-06	1	6A	Amended Outer Lead Surface process.	

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Product Specifications EXT

AN7135

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EXTERNAL ISSUE

Total Page

Page No. 1

Structure	Silicon Monolithic Bipolar IC
Appearance	FP12S Pin Plastic Package (with Fin)
Application	Low Frequency Power Amplifier
Function	7.5W(3Ω) x 2 Channel Power amplifier With Standby Function

A	Absolute Maximum Ratings						
No.	Item Symbol Ratings				Note		
1	Storage Temperature	Tstg	-55 ~ +150	°C	1		
2	Operating Ambient Temperature	Topr	-30 ~ +75	°C	1		
3	Operating Ambient Pressure	Popr	1.013x10 ⁵ ±0.61x10 ⁵	Pa			
4	Operating Constant Acceleration	Gopr	9,810	m/s²			
5	Operating Shock	Sopr	4,900	m/s²			
6	Supply Voltage	Vcc	24	V			
7	Supply Current	Icc	4.0	A			
8	Power Dissipation	P_{D}	62.5	W	2		

Operating Supply Voltage Range	Vcc	5V ~ 18V	Note 3

Note 1: The temperature of all item shall be Ta=25°C except storage temperature and operating ambient temperature.

Note 2: $R_{\theta j-c} = 2.0^{\circ} C/W$

Note 3: 24V during no signal.

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Product Specifications AN7135

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Total Page	7
Page No.	2

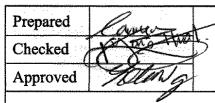
В	Electrical Characteristics (Unless otherwise specified, the ambient temperature is 25°C ± 2°C)								
No.	Item	C11	Test	Conditions	Limits			TT	N T - 4 -
NO.	nem	Symbol	Cir- cuit		min	typ	max	Unit	Note
1	Quiescent Circuit Current	Icq	1	V _{IN} =0mV	=	14	20	mA	
2	Output Noise Voltage	Vno	1	$V_{IN}=0$ mV, $R_g=10$ k Ω	-	0.25	0.50	mV	1
3	Voltage Gain	Gv	1	V _{IN} =3mV	42.5	44.5	46.5	dB	
4	Total Harmonic Distortion	THD	1	V _{IN} =3mV	-	0.40	0.75	%	
5	Maximum Power Output	Po	1	THD=10%	7.0	7.5		W	
6	Channel Balance	СВ	1	V _{IN} =3mV	-1	0	+1	dB	
7	Ripple Rejection	RR	1	Vcc(ripple) = 280 mV f(ripple) = 120 Hz Rg = 0Ω Sine wave	45	50	-	dВ	1
8	Input Offset Voltage	Vin (o.s)	1	Input pin open	•	10	30	mV	
9	Standy-by current	Istb	1	Pin 3 open	_		30	μΑ	

< Vcc = 15.0V, RL = 3Ω , Freq = 1kHz, Driving 2 channel >

Note 1) Use filter 15Hz ~ 30kHz (12dB/OCT) when measurement.

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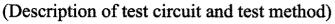
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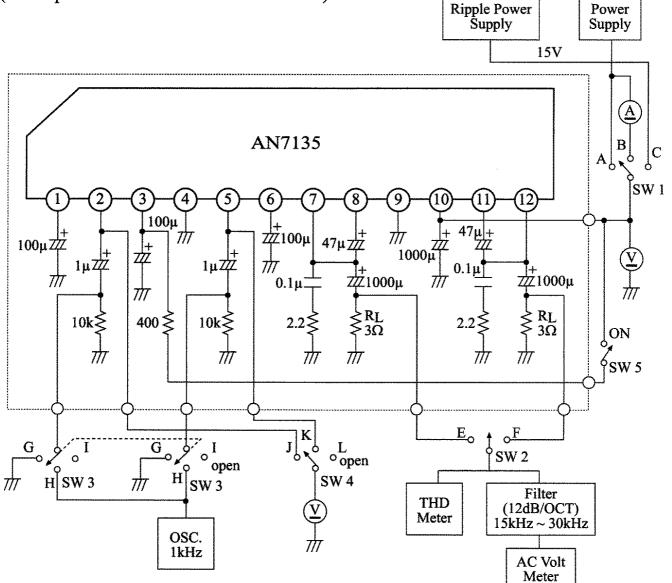


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ITEM	SW 1	SW 2	SW 3	SW 4	SW 5
B1	В	_	G	L	ON
B2	Α	E or F	I	L	ON
B3	Α	E or F	Н	L	ON
B4	Α	E or F	н	L	ON
B5	A	E or F	Н	L	ON
B 6	A	E or F	H	L	ON
B 7	C	E or F	G	L	ON
B8	A	_	I	J or K	ON
B9	Α	-	I	-	OFF

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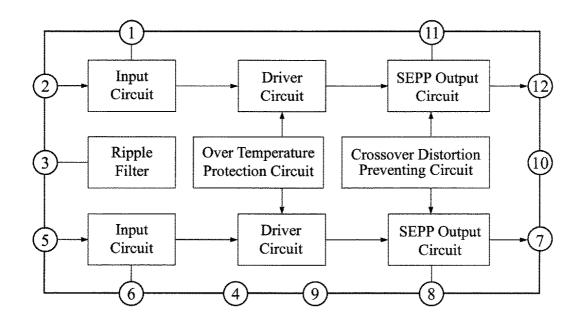
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Product Specifications

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Circuit Function Block Diagram



Pin Descriptions

Pin No.	Description	Pin No.	Description
1	Channel 1 negative feedback	7	Channel 2 output
2	Channel 1 input	8	Channel 2 bootstrap
3	Repple filter / Stand-by	9	GND (Output side)
4	GND (Input side)	10	Power supply
5	Channel 2 input	11	Channel 1 bootstrap
6	Channel 2 negative feedback	12	Channel 1 output

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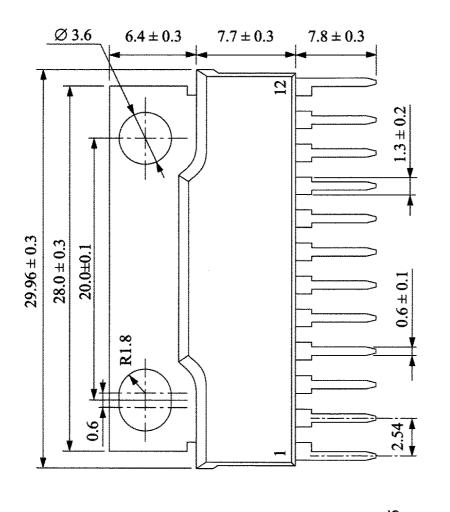
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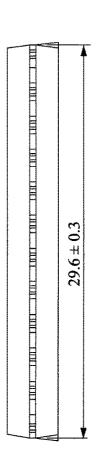
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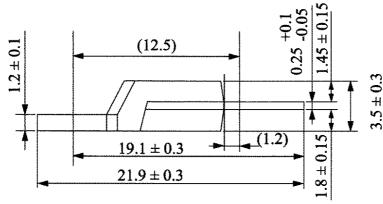
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Package Name FP 12S

Unit: mm







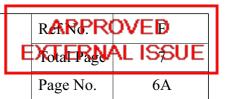
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Prepared	Yiap Shi Hui				
Checked	John Ng				
Approved	T. Sugimura				

Product Specifications (Leadfree)

AN7135



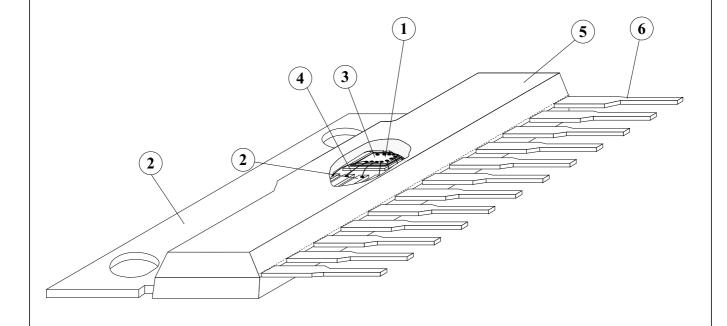
(Structure Description)

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Chip surface passivation	SiN,	PSG,	Others ()	1
Lead frame material	Fe group,	Cu group,	Others ()	2,6
Inner lead surface process	(Ag plating,	Au plating,	Others ()	2
Outer lead surface process	General Custome SC Buyback:	er: Solder Plating (98Sn-2E Solder Dip (95.5Sn-2Ag			6
Chip mounting method	Ag paste,	Au-Si alloy, Solder	(95.5Pb-2.5Ag-2S	(n)**,	3
Wire bonding method	Thermalsonic	bonding,	Others ()	4
Wire material	Au,		Others ()	4
Mold material	Epoxy,		Others ()	5
Molding method	Transfer mole	d, Multiplunger mold,	Others ()	5
Fin material	Cu group,		Others ()	7

Package FP12S

** Under RoHS exemption clause, Lead (Pb) in high melting temperature type solder (ie. tin-lead solder alloy containing more than 85% of lead), is exempted until 2010.



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Product Specifications

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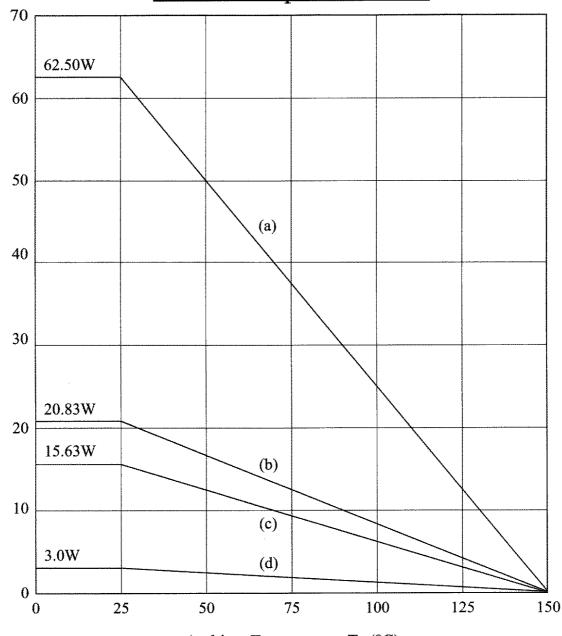
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(a) 62.50W Unlimited heatsink (θ j-c = 2°C/W)

- (b) 20.83W (θf=4.0°C/W)

 Heat sink of 100cm² x 3mm Al (black lacquer) or 200cm² x 2mm Al (without lacquer)
- (c) 15.63W (θf=6.0°C/W)
 Heat sink of 100cm² x 2mm Al (without lacquer)
- (d) 3.0W at Ta=30°C(θ j-a=40°C/W) No Heat sink

Power Dissipation PD -Ta



Ambient Temperature, Ta (°C)

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Power Dissipation, PD (W)